Attorney Docket No. 042261

REMARKS

Claims 1-13 are pending in the application. Claims 8-10 have been withdrawn. Claims

11-13 have been added. No claims have been amended. In light of the following remarks,

applicants earnestly solicit favorable reconsideration.

On the Merits

The Office Action has maintained the rejections of claims 1, 2 and 4-6 under 35 U.S.C. §

102(b) as being anticipated by Takeuchi (US Patent 5,641,696). Dependent claims 3 and 7 have

been rejected under 35 U.S.C. § 103(a) as being unpatentable over Takeuchi in view of Taka et

al. (US Patent 4,853,342).

<u>Independent Claim 1</u>

Independent claim 1 requires in part:

[T]he step of forming the first junction includes at least a first ion implantation which is carried out with a first acceleration energy and a first does, and a second ion implantation which is carried out with a second acceleration energy higher

than the first acceleration energy and a second dose lower than the first dose.

In applicant's response to the Examiner filed on November 6, 2006 the response

indicated:

Takeuchi discloses a first ion-implantation is carried out at an acceleration energy 60KeV and a dose $3\times10^{15}/cm^2$ (column 10, lines 13-19) and a second ion-implantation is carried out at an acceleration energy 30KeV and a dose

 $5 \times 10^{14} / cm^2$ (column 10, lines 38-42). Emphasis added.

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Thus, *Takeuchi* discloses a second ion implantation at a lower energy and lower

dose than the first ion implantation.

The Examiner responded by stating in the Advisory Action dated November 29, 2006:

since the second concentration/mass of the second ion implantation is lower than

the first concentration/mass of the first ion implantation, the second acceleration

energy is then considered to be higher than the first acceleration energy because one skilled in the art would know that the acceleration energy is proportional to

the concentration/mass, this means the smaller concentration/mass of the ion

implantation the higher acceleration energy of ion implantation. Emphasis

added.

However, contrary to the Examiner's position, Takeuchi specifically discloses a lower

implantation energy in the second implantation (30 KeV as opposed to 60 KeV) in column 10,

lines 38-42. The Examiner's position that *Takeuchi* discloses a higher implantation energy

therefore contradicts the reference. Applicants respectfully traverse the rejection of independent

claim 1.

Dependent Claims 2-7 and 11-13:

As claims 2-7 and 11-13 each depend from independent claim 1, the arguments set forth

above regarding claim 1 also apply to its dependent claims. As such, applicants respectfully

traverse the rejection.

In view of the aforementioned amendments and accompanying remarks, Applicant

submits that the claims, as herein amended, are in condition for allowance. Applicant requests

such action at an early date.

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If the Examiner believes that this application is not now in condition for allowance, the Examiner is requested to contact Applicant's undersigned agent to arrange for an interview to

expedite the disposition of this case.

If this paper is not timely filed, Applicant respectfully petitions for an appropriate

extension of time. The fees for such an extension or any other fees that may be due with respect

to this paper may be charged to Deposit Account No. 50-2866.

Respectfully submitted,

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